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ISL9R1560P2_F085

15A, 600V Stealth Rectifier

Features

- High Speed Switching ($t_{rr}=30\text{ns(Typ.)}$ @ $I_F=15\text{A}$)
- Low Forward Voltage ($V_F=2.2\text{V(Max.)}$ @ $I_F=15\text{A}$)
- Avalanche Energy Rated
- AEC-Q101 Qualified

Applications

- Automotive DCDC Converter
- Automotive On Board Charger
- Switching Power Supply
- Power Switching Circuits

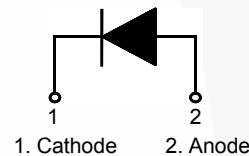
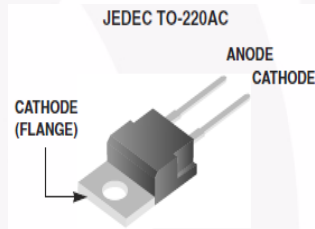
Max Ratings (600V, 15A)

The ISL9R1560P2_F085 is a Stealth™ diode with soft recovery characteristics ($t_{rr} < 30\text{ns}$). It has a low forward-voltage drop and is of silicon nitride passivated, ion-implanted, epitaxial construction.

This device is intended for use as a freewheel/clamping diode in various automotive switching power supplies and other power switching applications.

Its low stored charge as well as Stealth™ and soft recovery characteristics minimize ringing and electrical noise while reduce the overall power loss.

Pin Assignments



Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{RRM}	Peak Repetitive Reverse Voltage	600	V
V_{RWM}	Working Peak Reverse Voltage	600	V
V_R	DC Blocking Voltage	600	V
$I_{F(AV)}$	Average Rectified Forward Current @ $T_C = 25^\circ\text{C}$	15	A
I_{FSM}	Non-repetitive Peak Surge Current (Halfwave 1 Phase 50Hz)	45	A
E_{AVL}	Avalanche Energy (1A, 40mH)	20	mJ
T_J, T_{STG}	Operating Junction and Storage Temperature	- 55 to +175	$^\circ\text{C}$

Thermal Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Max	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	0.93	$^\circ\text{C/W}$
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	62	$^\circ\text{C/W}$

Package Marking and Ordering Information

Device Marking	Device	Package	Tube	Quantity
ISL9R1560P2	ISL9R1560P2_F085	TO-220AC	-	50

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

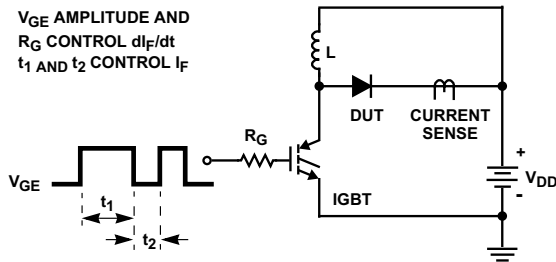
Symbol	Parameter	Conditions	Min.	Typ.	Max	Units	
I_R	Instantaneous Reverse Current	$V_R = 600\text{V}$	$T_C = 25^\circ\text{C}$	-	-	100	μA
			$T_C = 175^\circ\text{C}$	-	-	1000	μA
V_{FM}^1	Instantaneous Forward Voltage	$I_F = 15\text{A}$	$T_C = 25^\circ\text{C}$	-	1.65	2.2	V
			$T_C = 175^\circ\text{C}$	-	1.24	1.7	V
t_{rr}^2	Reverse Recovery Time	$I_F = 1\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_R = 390\text{V}$	$T_C = 25^\circ\text{C}$	-	22	30	ns
			$T_C = 175^\circ\text{C}$	-	127	-	ns
t_a	Reverse Recovery Time	$I_F = 15\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_R = 390\text{V}$	-	17	-	ns	
t_b	Reverse Recovery Time	$I_F = 15\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_R = 390\text{V}$	-	13	-	ns	
Q_{rr}	Reverse Recovery Charge	$I_F = 15\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_R = 390\text{V}$	-	48	-	nC	

Notes:

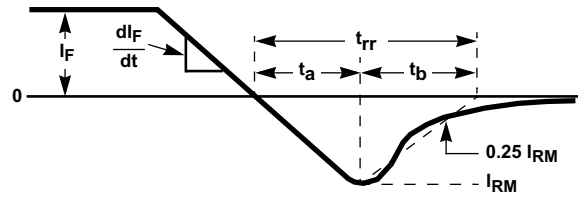
1. Pulse : Test Pulse width = $300\mu\text{s}$, Duty Cycle = 2%
2. Guaranteed by design

Test Circuit and Waveforms

t_{rr} Test Circuit

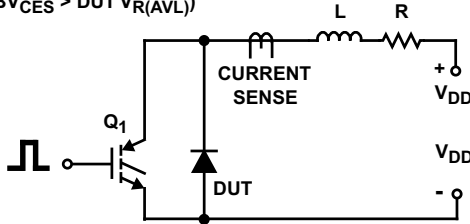


t_{rr} Waveforms and Definitions

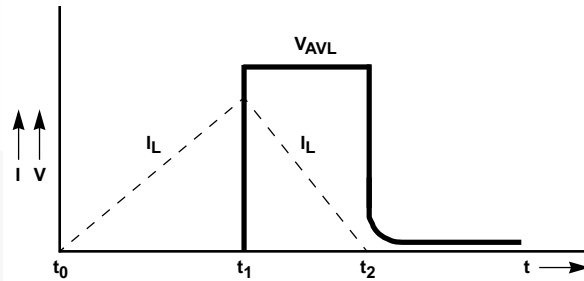


Avalanche Energy Test Circuit

- $I = 1\text{A}$
- $L = 40\text{mH}$
- $R < 0.1\Omega$
- $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$
- $Q_1 = \text{IGBT (BV}_{CES} > \text{DUT } V_{R(AVL)})$



Avalanche Current and Voltage Waveforms



Typical Performance Characteristics

Figure 1. Typical Forward Voltage Drop vs. Forward Current

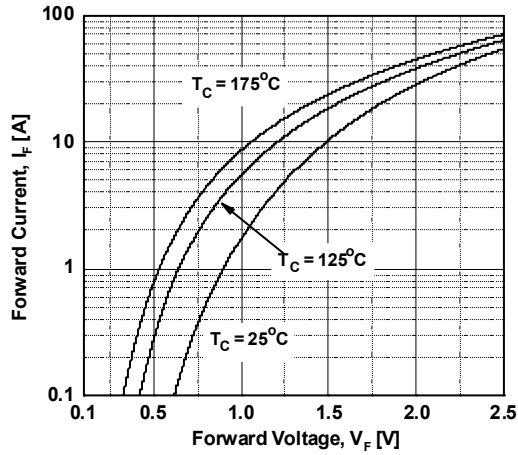


Figure 2. Typical Reverse Current vs. Reverse Voltage

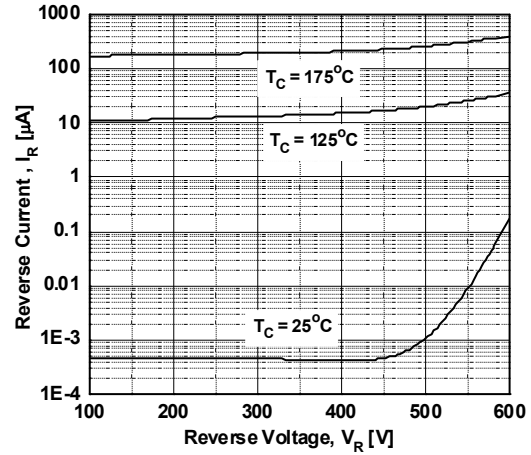


Figure 3. Typical Junction Capacitance

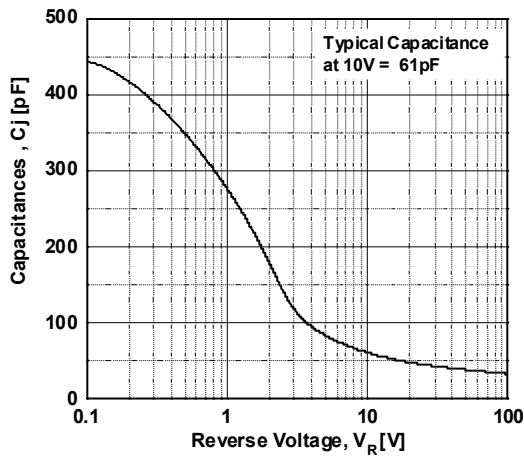


Figure 4. Typical Reverse Recovery Time vs. di/dt

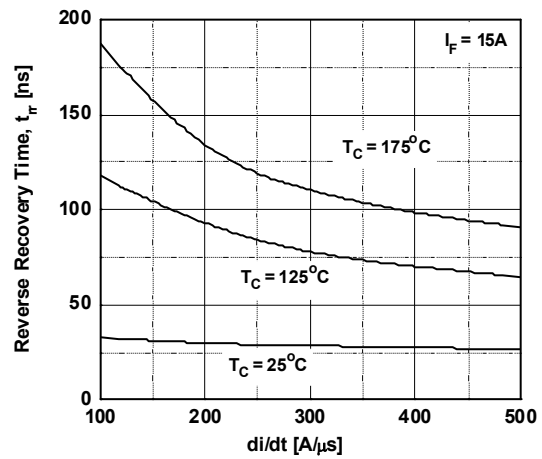


Figure 5. Typical Reverse Recovery Current vs. di/dt

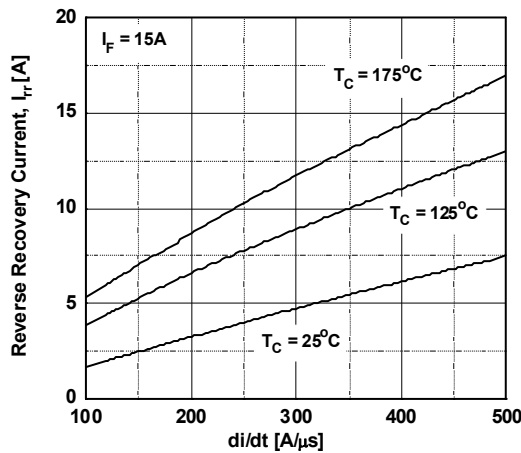
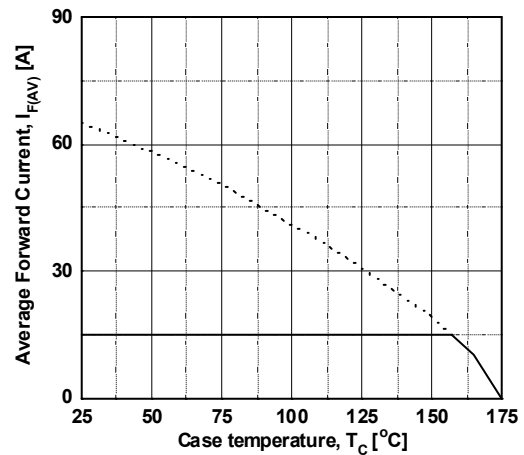


Figure 6. Forward Current Derating Curve



Typical Performance Characteristics (Continued)

Figure 7. Reverse Recovery Charge

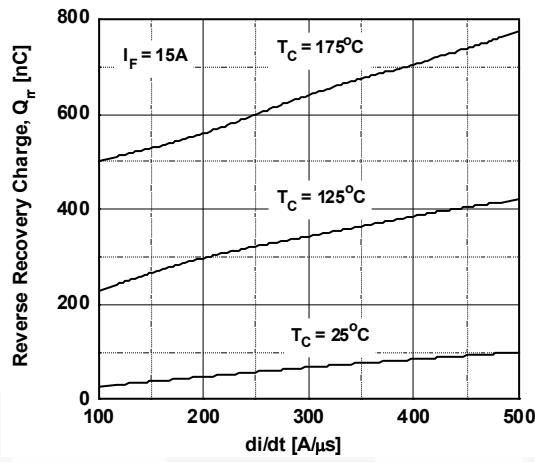
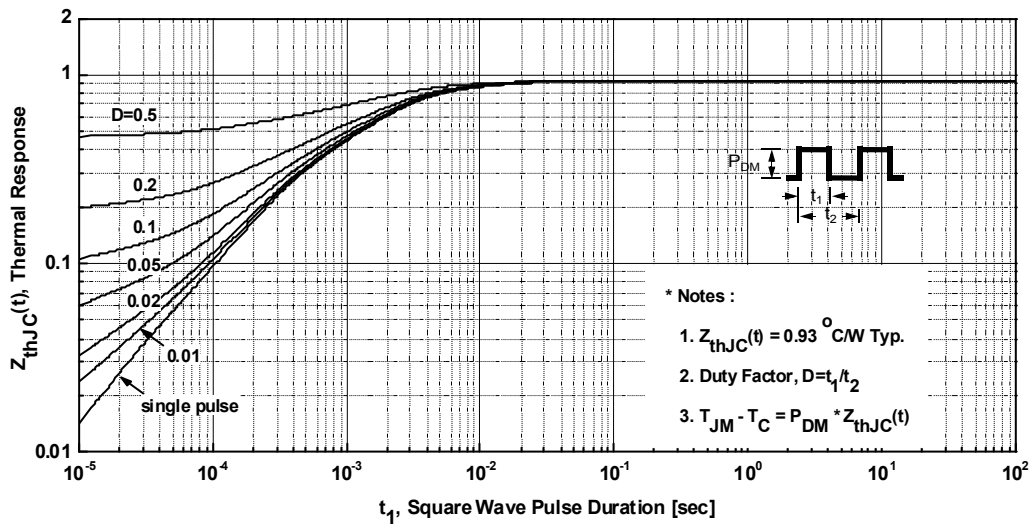
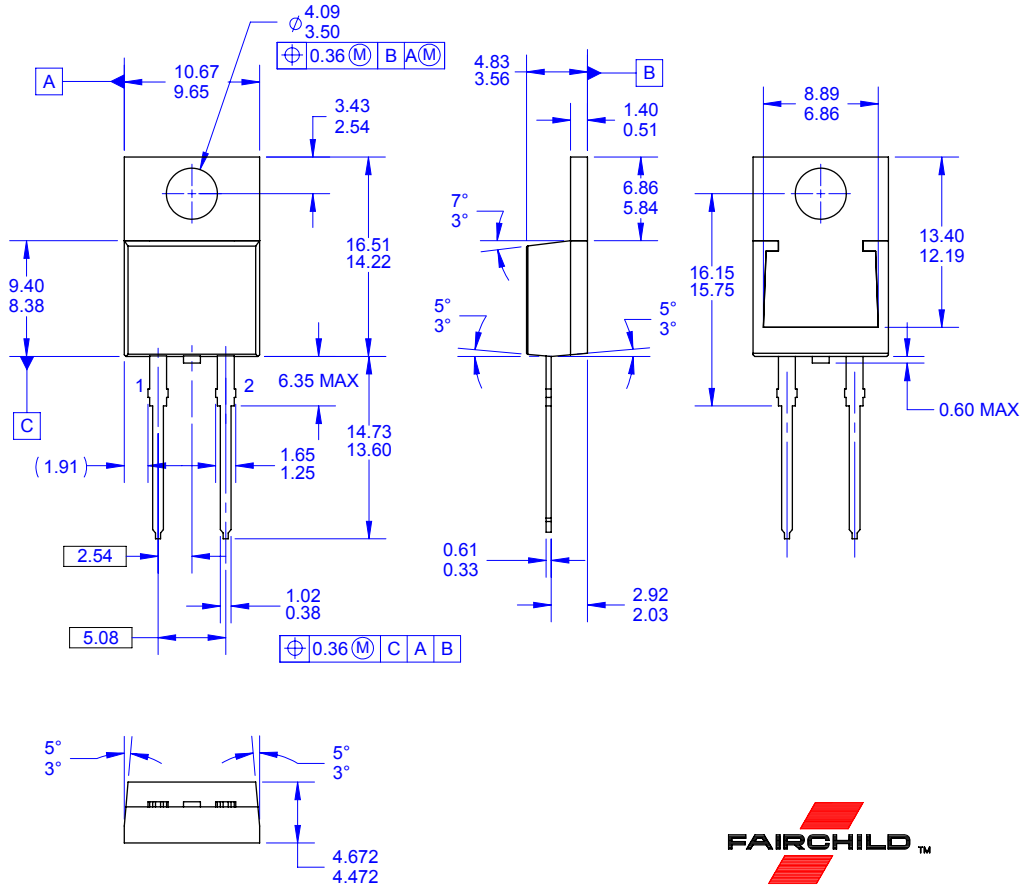


Figure 8. Transient Thermal Response Curve



Mechanical Dimensions

TO-220-2L



NOTES:

- A. PACKAGE REFERENCE: JEDEC TO220,ISSUE K, VARIATION AC,DATED APRIL 2002.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSION AND TOLERANCE AS PER ASME Y14.5-2009.
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- E. DRAWING FILE NAME: TO220A02REV04.

Dimensions in Millimeters





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